NSN 5961-01-179-3468



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-179-3468 **Inclosure Material:** Metal **Overall Length:** 0.190 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.220 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 drain to gate voltage **Current Rating Per Characteristic:** 10.00 milliamperes gate current **Power Rating Per Characteristic:** 300.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Precious Material And Location:** Lead surfaces gold **Precious Material:** Gold

Terminal Type And Quantity: 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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